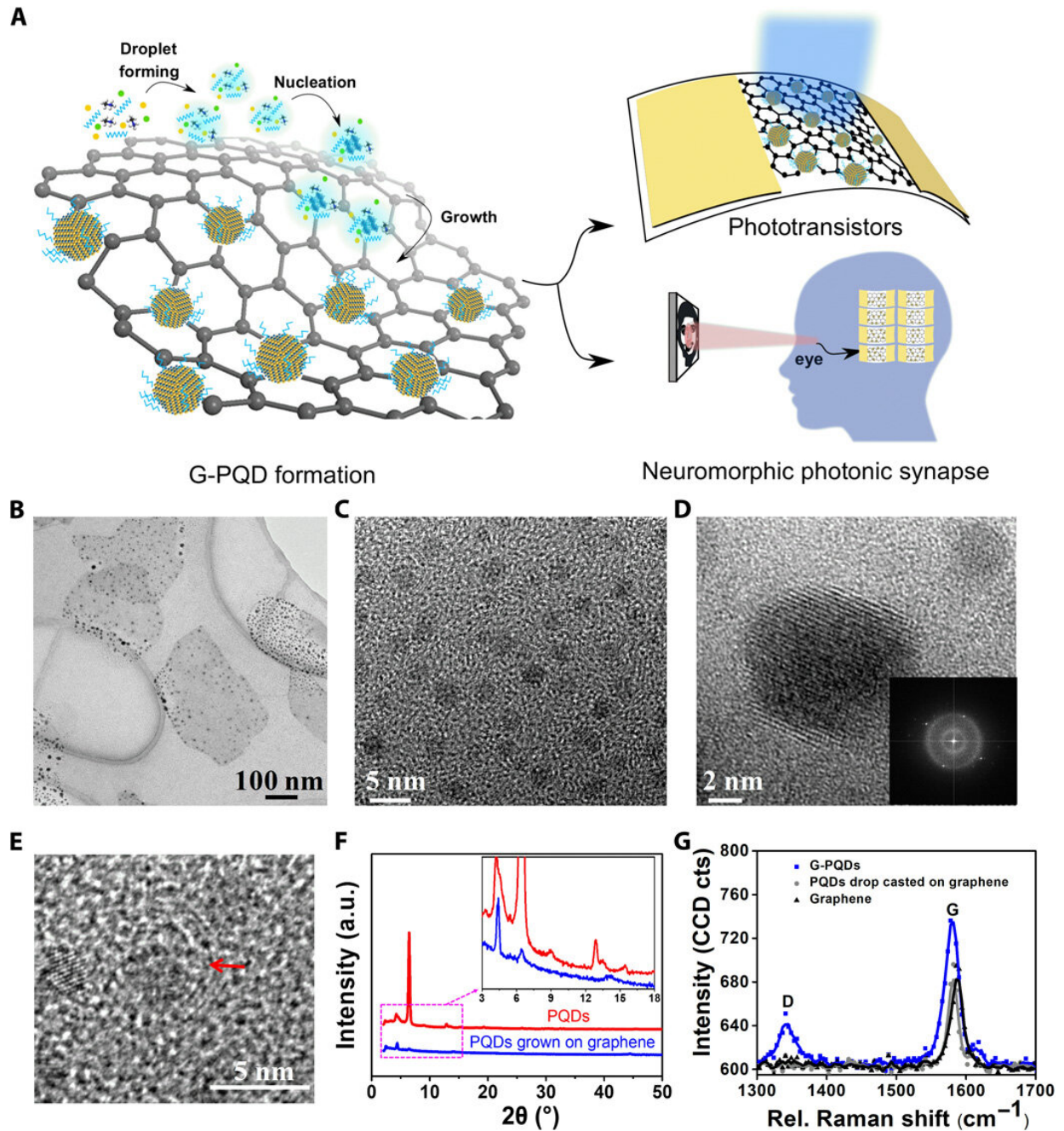


# **Building ultrasensitive and ultrathin phototransistors and photonic synapses using hybrid superstructures**

February 26 2020, by Thamarasee Jeewandara

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G-PQD superstructure. (A) Schematic showing the growth of PQDs on graphene to form the G-PQD superstructure and the proposed applications. (B) TEM image of PQDs grown on a single layer of graphene sheets. (C) TEM image of the PQDs distributed on the G-PQD superstructure. (D) High-resolution TEM (HRTEM) image of the PQDs grown on graphene. Inset shows the corresponding FFT image. (E) HRTEM image of stress-induced changes in the graphene lattice due to the growth of PQDs (red arrow indicates distortion). (F)

XRD spectra of pristine PQDs (red) and G-PQDs (blue) grown on silicon [inset: enlarged region; units remain the same,  $3.3^\circ$ ,  $4.4^\circ$ ,  $6.5^\circ$ ,  $9.0^\circ$ , and  $15.4^\circ$  corresponding to (011), (101), (201), (141), and (100) crystal planes, respectively]. a.u., arbitrary units. (G) Raman spectra of pristine graphene (black), PQDs drop casted on graphene (gray), and PQDs grown on graphene (blue). CCD, charge-coupled device. Credit: Science Advances, doi: 10.1126/sciadv.aay5225

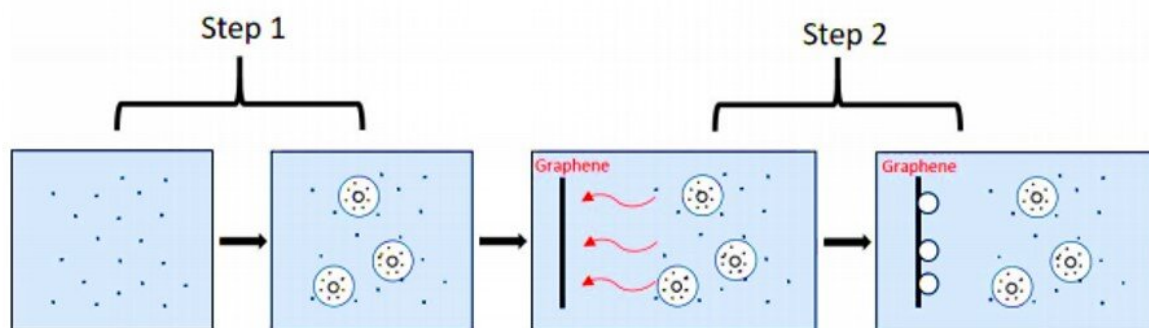
Organic-inorganic halide perovskite quantum dots (PQDs) form an attractive class of materials for optoelectronic applications. Their charge transport properties are, however, inferior compared to materials such as graphene. Conversely, graphene contains a charge generation efficiency that is too low for applications in optoelectronics. In a new report, Basudev Pradhan and a research team at the Nanoscience Technology Center, and the departments of Optics and Photonics, Materials Science Engineering, Physics and Chemistry at the University of Central Florida, U.S., Developed an ultrathin photon transistor and photonic synapses using graphene-PQD (graphene-perovskite quantum dot; G-PQD) superstructures. To prepare the superstructures they grew PQDs directly from a graphene lattice. Phototransistors made of G-PQDs exhibited excellent responsivity and specific detectivity. The light-assisted memory effects of the superstructures allowed photonic synaptic behavior for neuromorphic computing, which the team demonstrated through facial recognition applications with the assistance of machine learning. Pradhan et al. expect the G-PQD superstructure to bolster new directions to develop highly effective optoelectronic devices.

Graphene has emerged as a dream material for electronics and optoelectronics due to its broad spectral bandwidth, excellent carrier transport properties with [high mobility](#), exceptional stability and outstanding flexibility. Materials scientists have developed many composites and devices for applications in energy harvesting, storage,

[photodetectors and transistors](#). However, a single layer of graphene can only absorb 2.3 percent of incident visible light, critically impeding their use in [optoelectronic and photonic devices](#). In contrast, organic-inorganic PQDs have risen as attractive materials for applications in optoelectronics due to [their unique characteristics](#), although their charge transport remains inferior compared to graphene.

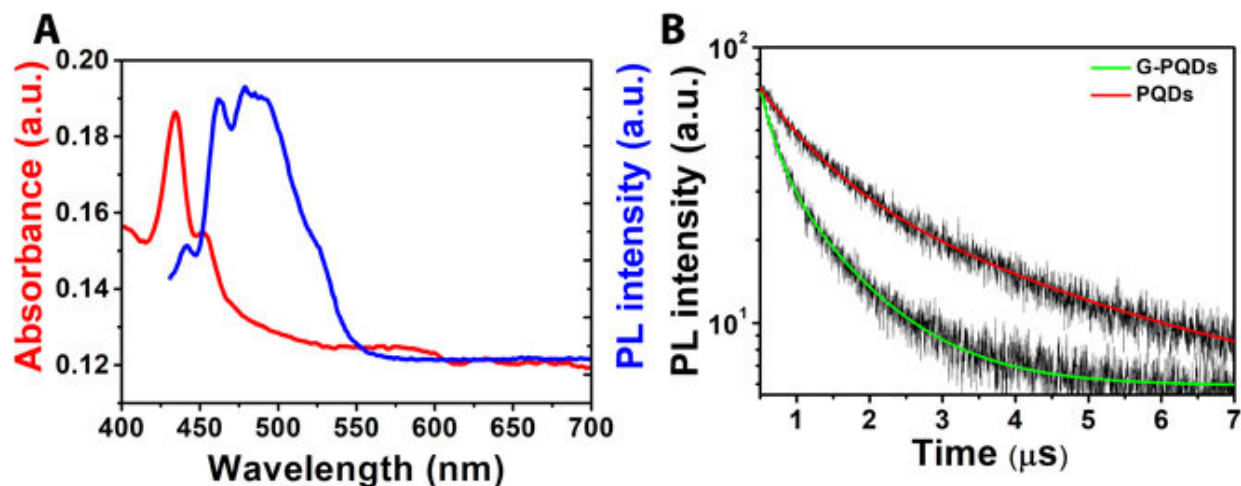
## Growing PQDs from a graphene lattice

Pradhan et al. explored the strong photogeneration efficiency of methylammonium lead bromide PQDs in this work by growing PQDs from the lattice of single-layer graphene using a defect-mediated process. Since PQDs can absorb light and generate charge carriers, the rationale helped design the hybrid superstructures. The team implemented the thin superstructures in a phototransistor geometry to produce a photoresponsivity of  $1.4 \times 10^8 \text{ AW}^{-1}$  and a specific detectivity of  $4.72 \times 10^{15} \text{ Jones}$  at 430 nm; which was by far the best responsivity and detectivity recorded across similar devices to date.



PQD growth mechanism on single-layer graphene. Credit: Science Advances, doi: 10.1126/sciadv.aay5225

The work is highly promising to develop extremely efficient optoelectronic materials for high-speed communications, sensing, ultra-sensitivity cameras, [high-resolution imaging and displays](#). The behavior of graphene-PQD (G-PQD) superstructures in the form of a photonic synapse is also critical for pattern recognition. The results support the development of a hardware unit for neuromorphic architecture that mimics the human brain—for a range of exciting applications. Pradhan et al. used [ligand-assisted reprecipitation](#) (LARP) to produce PQDs with a very high [photoluminescence quantum yield](#), and controlled the size and morphology of the PQD products. The team initiated growth of PQDs directly on the active sites of the graphene monolayers to form the superstructures. During the process, they added an antisolvent toluene onto a graphene layer wetted with [perovskite](#) precursors to initiate seeding, and formed perovskite embryos on the graphene sheet required [for PQD crystal formation](#).

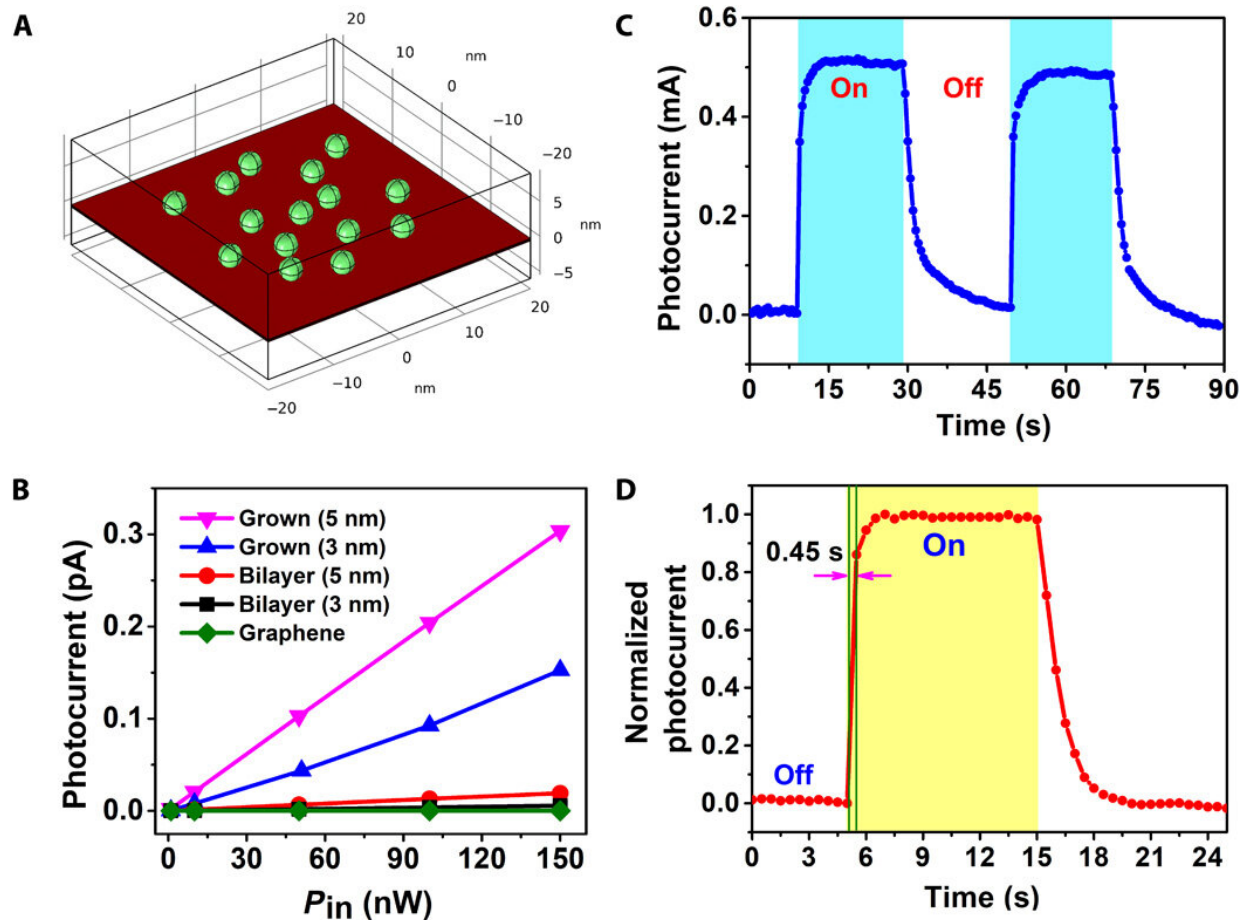


UV-vis and PL spectra. (A) Ultraviolet-visible (UV-vis) absorption (red) and PL spectra (blue) of the G-PQD superstructure film. (B) PL decay profiles of PQD (red) and G-PQD films (green). Credit: Science Advances, doi: 10.1126/sciadv.aay5225

## Developing highly sensitive, ultrathin phototransistors

The team analyzed the newly synthesized hybrid material (graphene PQDs) using [transmission electron microscopy](#) (TEM) to verify binding between the PQDs and graphene layers. They noted the presence of two different G-PQDs that absorbed visible wavelength at 434 nm and 451 nm, indicating their potential to form high-performing phototransistors detecting at blue illumination. Pradhan et al. tested the photophysical properties of the material relative to the excited-state dynamics of the G-PQD [superstructure](#) using [time-correlated single photon counting](#) (TCSPC) and observed an average fluorescence decay time of 749 ns. The superstructure showed enhanced sensitivity and an enhanced photocurrent compared to [previously reported photoresistors](#). The device could also act as a light-activated switch under white light illumination and the photocurrent rose quickly within a [response time](#) of 0.45 seconds after turning the light on. Longer response times resulted due to [more complex factors](#).





COMSOL simulation and transient photoresponse. (A) Schematic of COMSOL simulation of PQDs of size 3 nm grown on a graphene film. (B) Simulated photocurrent versus input power. (C) Transient photoresponse under light illumination on and off conditions. (D) Normalized photocurrent response to on and off illumination. Credit: Science Advances, doi: 10.1126/sciadv.aay5225

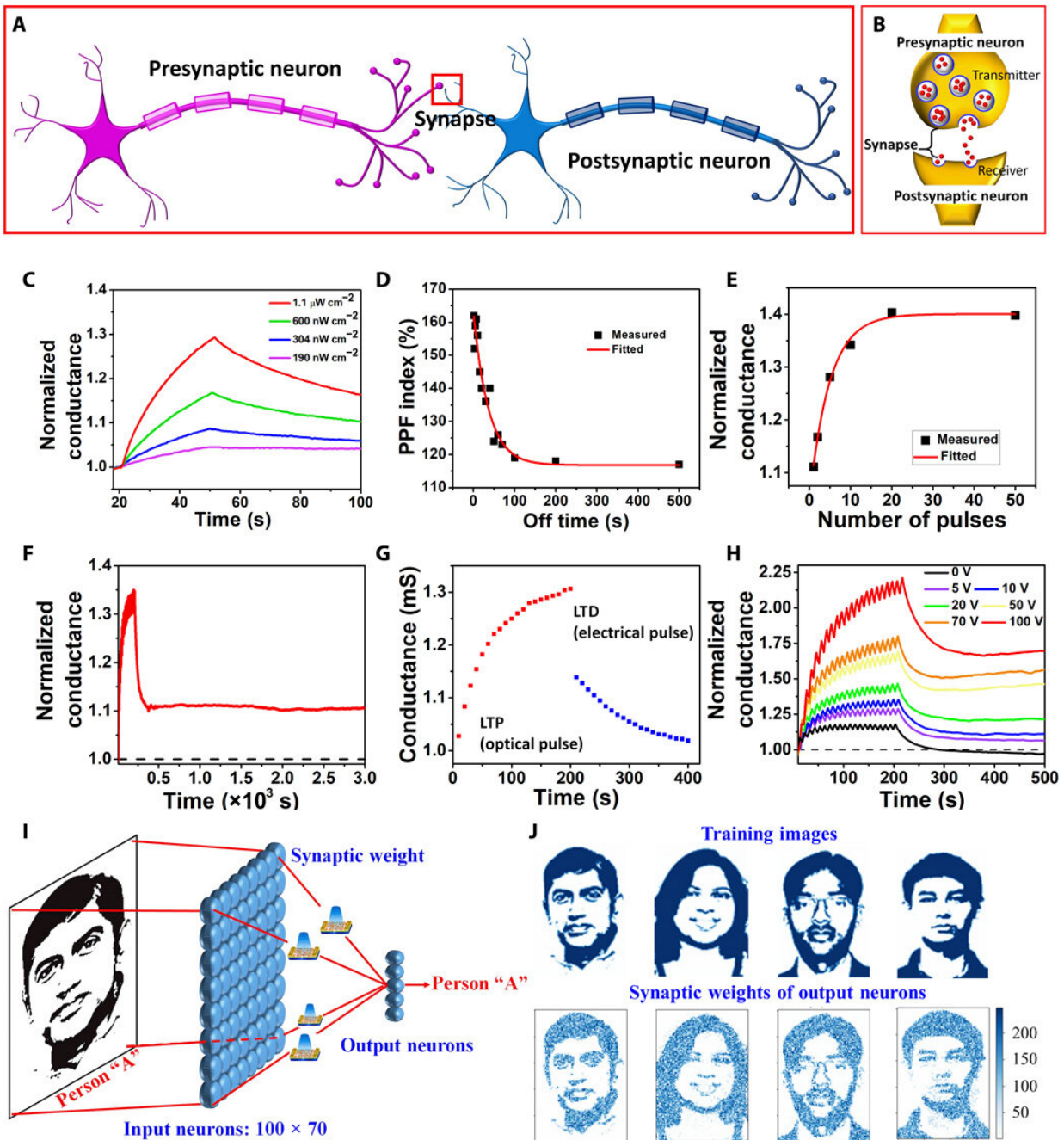
## Applications of neuromorphic photonic synapses during facial recognition.

Since traditional [von Neumann architecture](#) or Princeton architecture; a computer architecture developed by mathematician and physicist [John von Neumann](#) is both time and power consuming for data transport at

present. The existing limits of performance and scalability between the memory and processor are popularly referred to as the [von Neumann bottleneck](#). The device had caused major drawbacks in data-centric applications of real-time image recognition, data classification and natural language processing. [Neuromorphic computing](#) is therefore an emerging—superior platform that can outperform the von Neumann architecture. In the setup, the synapse can typically act as a channel of communication between two neurons.

In this instance, the G-PQD superstructure acted as an artificial photonic synapse; where the pre-synaptic signal was based on the external light stimuli in the form of optical pulses and the post-synaptic signal was the current obtained across the G-PQD channel to [keep the drain source and gate voltage fixed](#). The embedded optical information, detection processing and retention capabilities of the G-PQD synaptic devices formed a potential candidate for human visual memory in fields of pattern recognition. Pradhan et al. constructed a [spiking neural network](#) to perform unsupervised machine learning and face recognition using [Python](#). The team used four portraits of people to train the neural network and showed that an increased use of output neurons alongside longer training time could achieve higher rates of facial recognition.





Photonic synapse performance and facial recognition. (A) Anatomy of two interconnected human neurons via a synapse (red box). (B) Schematic representation of biological synapses. (C) Transient characteristic of the device ( $V_D = 0.5$  V and  $V_G = 10$  V) showing the change in conductance due to a single pulse of light of pulse width 30 s for varying light intensity. (D) PPF index of the device ( $V_D = 0.5$  V and  $V_G = 10$  V) due to varying off time between two consecutive light pulses having on time of 5 s. (E) Transient characteristic of the

device ( $V_D = 0.5$  V and  $V_G = 10$  V) showing the change in conductance due to varying number of light pulses having on and off time of 5 and 5 s, respectively. (F) Retention of the long-term potentiated device ( $V_D = 0.5$  V and  $V_G = 10$  V) for  $3 \times 10^3$  s after application of 20 optical pulses (on and off time of 5 and 5 s, respectively). (G) Nonvolatile synaptic plasticity of the device ( $V_G = 10$  V) showing LTP by train of optical pulses (on and off time of 5 and 5 s, respectively) at  $V_D = 0.5$  V and LTD by a train of electrical pulses ( $-0.5$  V, on and off time of 1 and 1 s, respectively) at  $V_D$ . (H) Gate-dependent transient characteristic of the device ( $V_D = 0.5$  V) after application of 20 optical pulses (on and off time of 5 and 5 s, respectively). (I), Neuron network structure for face recognition. Photo credit: Sreekanth Varma and Basudev Pradhan, UCF. (J) Real images (top) for training and the synaptic weights of certain corresponding output neurons (bottom). Photo credit (from left to right): Sreekanth Varma and Basudev Pradhan, UCF; Avra Kundu and Basudev Pradhan, UCF; Basudev Pradhan, UCF; and Basudev Pradhan, UCF. Credit: Science Advances, doi: 10.1126/sciadv.aay5225

In this way, Basudev Pradhan and colleagues developed extremely thin superstructures based on hybrid materials of PQDs grown from a graphene lattice using a defect-mediated crystal growth technique. They obtained highly enhanced charge transfer due to the combined  [\$\pi\$ -electron clouds](#) of PQDs and [graphene](#). The resulting devices exhibited high performances for phototransistors and photonic synapses, which the team further validated using simulations. The team intend to extend their approach to other 2-D materials including [transition metal dichalcogenides](#) and other [heterostructures](#). The work will open the door to a new class of high-performance superstructure materials suited for multiple electronic and optoelectronic applications, beneficial for facial recognition and neuromorphic computing.

**More information:** Basudev Pradhan et al. Ultrasensitive and ultrathin phototransistors and photonic synapses using perovskite quantum dots

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